

# isc N-Channel MOSFET Transistor

#### **FEATURES**

- Drain Current : I<sub>D</sub>= 3.0A@ T<sub>C</sub>=25℃
- Drain Source Voltage
  - : V<sub>DSS</sub>= 100V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)}$  = 0.35  $\Omega$  (Max) @  $V_{GS}$ = 10V
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **DESCRIPTION**

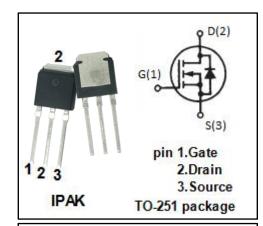
 motor drive, DC-DC converter, power switch and solenoid drive.

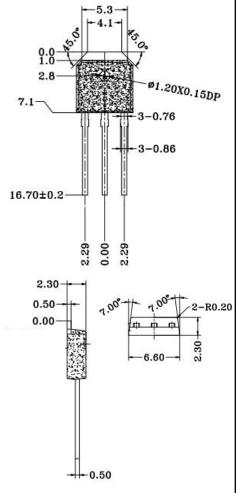
### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	100	V
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±20	V
I <sub>D</sub>	Drain Current-Continuous	3.0	А
I <sub>DM</sub>	Drain Current-Single Pluse	12	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃ 20		W
TJ	Max. Operating Junction Temperature -55~150		$^{\circ}$
T <sub>stg</sub>	Storage Temperature -55~150		${\mathbb C}$

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	6.25	°C/W





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2SK4018

#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 10mA	100		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> = 1mA	0.8	2.0	V
R <sub>DS(on)1</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 2.0A V <sub>GS</sub> = 4V; I <sub>D</sub> = 2.0A		0.35 0.45	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±16V;V <sub>DS</sub> = 0		±10	uA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 100V; V <sub>GS</sub> = 0		0.1	mA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 3A; V <sub>GS</sub> = 0		1.5	V

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